



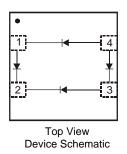
#### 0.5A SBR<sup>®</sup> BRIDGE SUPER BARRIER RECTIFIER

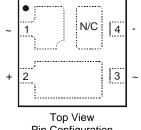
## **Features**

- Ultra Low Leakage Current
- **Excellent High Temperature Stability**
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- Lead Free Finish, RoHS Compliant (Note 1)
- "Green" Device (Note 4)

#### **Mechanical Data**

- Case: DFN3030-4
- Case Material: Molded Plastic "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu Over Copper Lead Frame, Solderable per MIL-STD-202, Method 208 (C)
- Polarity: See Diagram
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.02 grams (approximate)





Pin Configuration

### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.			
Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> Vrwm V <sub>RM</sub>	100	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	70	V
Average Rectified Output Current	lo	500	mA
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (Per Diode)	I <sub>FSM</sub>	8	А

# **Thermal Characteristics**

Characteristic	Symbol	Тур	Max	Unit
Power Dissipation (Note 2)	PD	-	0.56	W
Thermal Resistance Junction to Ambient Air (Note 2)	$R_{\theta JA}$	-	222	°C/W
Thermal Resistance Junction to Ambient Air (Note 3)	$R_{\theta JA}$	-	149	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to	+150	°C

## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 4)	V <sub>(BR)R</sub>	100	-	-	V	I <sub>R</sub> = 250 μA
Forward Voltage (Per Diode)	VF	-	0.54 0.67 0.56	0.60 0.73 0.63	V	I <sub>F</sub> = 0.25A, T <sub>J</sub> = 25°C I <sub>F</sub> = 0.5A, T <sub>J</sub> = 25°C I <sub>F</sub> = 0.5A, T <sub>J</sub> = 125°C
Reverse Current (Note 4) (Per Diode)	I <sub>R</sub>	-	0.3 32	25 250	μΑ	V <sub>R</sub> = 100V, T <sub>J</sub> = 25°C V <sub>R</sub> = 100V, T <sub>J</sub> = 125°C

1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see EU Directive 2002/95/EC Annex Notes. Notes:

2. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.

3. Polymide PCB, 2 oz. copper; minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.

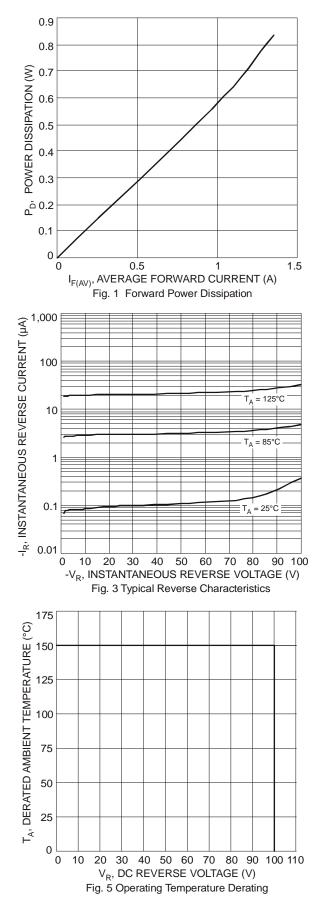
4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php

5. Short duration pulse test used to minimize self-heating effect.

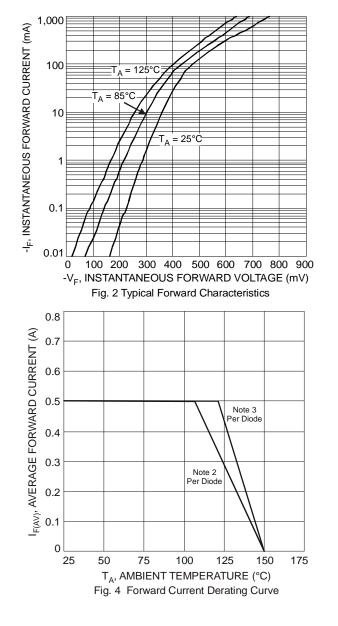
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## SBR05M100BLP



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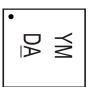


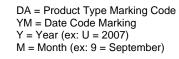
## Ordering Information (Note 6)

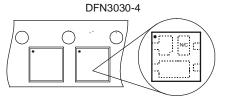
Fait Nulliber	Case	Packaging
SBR05M100BLP-7	DFN3030-4	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



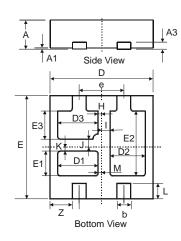




Date Code Key

Year	2007	20	08	2009	2010	20	11	2012	2013	20	14	2015
Code	U	١	/	W	Х	,	Y	Z	А		3	С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

## **Package Outline Dimensions**

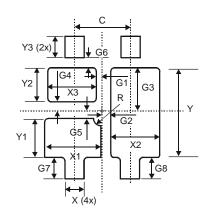


DFN3030-4					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.02		
A3	-	-	0.15		
b	0.35	0.45	0.40		
D	2.90	3.10	3.00		
D1	1.075	1.275	1.175		
D2	0.925	1.125	1.025		
D3	1.075	1.275	1.175		
E	2.90	3.10	3.00		
е	-	-	1.30		
E1	0.615	0.815	0.715		
E2	1.78	1.98	1.88		
E3	0.715	0.915	0.815		
Н	0.05	0.15	0.10		
I	0.20	0.30	0.25		
J	0.185	0.285	0.235		
ĸ	0.065	0.165	0.115		
L	0.30	0.60	0.45		
М	0.05	0.15	0.10		
Z	-	-	0.65		
All D	imens	ions in	mm		

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## **Suggested Pad Layout**



Dimensions	Value (in mm)
С	1.300
G1	0.100
G2	0.150
G3	0.830
G4	0.115
G5	0.135
G6	0.170
G7	0.500
G8	0.500
R	0.150
Х	0.500
X1	1.375
X2	1.225
X3	1.175
Y	1.980
Y1	1.015
Y2	0.715
Y3	0.650

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